

70V3579S4BC8

70V3579S4BC8 Information

•		 70V3579S4BC8 IDT, Integrated Device Technology Inc Integrated Circuits (ICs) Memory IC SRAM 1.125MBIT 4.2NS 256CABGA 256-LBGA For the pricing/inventory/lead time, please contact	
	For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



70V3579S4BC8 Specifications

Manufacturer Part Number	70V3579S4BC8
Manufacturer	IDT, Integrated Device Technology Inc
Category	Integrated Circuits (ICs)
	Memory
Package	256-LBGA
Series	-
Memory Type	Volatile
Memory Format	SRAM
Technology	SRAM - Dual Port, Synchronous
Memory Size	1.125Mb (32K x 36)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	-
Access Time	4.2ns
Voltage - Supply	3.15 V ~ 3.45 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	256-LBGA
Supplier Device Package	256-CABGA (17x17)
	Report errors?

70V3579S4BC8 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

70V3579S4BC8 Payment Methods



If you have any question about 70V3579S4BC8, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com